HALOGEN FREE

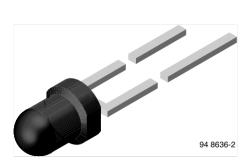
GREEN

(5-2008)



### Vishay Semiconductors

### Silicon NPN Phototransistor



#### **DESCRIPTION**

TEFT4300 is a silicon NPN phototransistor with high radiant sensitivity in black, T-1 plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

#### **FEATURES**

Package type: leadedPackage form: T-1

• Dimensions (in mm): Ø 3

High radiant sensitivity

Daylight blocking filter matched with 940 nm emitters

· Fast response times

• Angle of half sensitivity:  $\varphi = \pm 30^{\circ}$ 

 Package matched with IR emitter series TSUS4300 and TSAL4400

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **APPLICATIONS**

- Optical switches
- · Counters and sorters
- Interrupters
- Encoders
- · Position sensors

| PRODUCT SUMMARY |                      |         |                       |  |
|-----------------|----------------------|---------|-----------------------|--|
| COMPONENT       | I <sub>ca</sub> (mA) | φ (deg) | λ <sub>0.5</sub> (nm) |  |
| TEFT4300        | 3.2                  | ± 30    | 875 to 1000           |  |

#### Note

· Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |           |                              |              |  |  |
|----------------------|-----------|------------------------------|--------------|--|--|
| ORDERING CODE        | PACKAGING | REMARKS                      | PACKAGE FORM |  |  |
| TEFT4300             | Bulk      | MOQ: 5000 pcs, 5000 pcs/bulk | T-1          |  |  |

#### Note

• MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |             |      |  |
|--|--|-------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION                               | SYMBOL            | VALUE       | UNIT |  |
| Collector emitter voltage  |  | V <sub>CEO</sub>  | 70          | V    |  |
| Emitter collector voltage  |  | V <sub>ECO</sub>  | 5           | V    |  |
| Collector current  |  | I <sub>C</sub>    | 50          | mA   |  |
| Collector peak current   | $t_p/T = 0.5, t_p \le 10 \text{ ms}$         | I <sub>CM</sub>   | 100         | mA   |  |
| Power dissipation  | T <sub>amb</sub> ≤ 55 °C                     | P <sub>V</sub>    | 100         | mW   |  |
| Junction temperature   |  | Tj                | 100         | °C   |  |
| Operating temperature range  |  | T <sub>amb</sub>  | -40 to +100 | °C   |  |
| Storage temperature range  |  | T <sub>stg</sub>  | -40 to +100 | °C   |  |
| Soldering temperature  | $t \le 3$ s, 2 mm from case                  | T <sub>sd</sub>   | 260         | °C   |  |
| Thermal resistance junction/ambient  | Connected with Cu wire, 0.14 mm <sup>2</sup> | R <sub>thJA</sub> | 450         | K/W  |  |

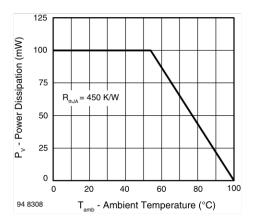


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                      |      |             |      |      |
|---|---|----------------------|------|-------------|------|------|
| PARAMETER   | TEST CONDITION  | SYMBOL               | MIN. | TYP.        | MAX. | UNIT |
| Collector emitter breakdown voltage   | I <sub>C</sub> = 1 mA   | V <sub>(BR)CEO</sub> | 70   |             |      | V    |
| Collector emitter dark current  | V <sub>CE</sub> = 20 V, E = 0   | I <sub>CEO</sub>     |      | 1           | 200  | nA   |
| Collector emitter capacitance   | $V_{CE} = 5 \text{ V, f} = 1 \text{ MHz, E} = 0$                                | C <sub>CEO</sub>     |      | 3           |      | pF   |
| Collector light current   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_{CE} = 5 \text{ V}$ | I <sub>ca</sub>      | 0.8  | 3.2         |      | mA   |
| Angle of half sensitivity   |   | φ                    |      | ± 30        |      | deg  |
| Wavelength of peak sensitivity  |   | λρ                   |      | 925         |      | nm   |
| Range of spectral bandwidth   |   | λ <sub>0.5</sub>     |      | 875 to 1000 |      | nm   |
| Collector emitter saturation voltage  | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $I_C = 0.1 \text{ mA}$ | V <sub>CEsat</sub>   |      |             | 0.3  | V    |
| Turn-on time  | $V_{S} = 5 \text{ V}, I_{C} = 5 \text{ mA}, R_{L} = 100 \Omega$                 | t <sub>on</sub>      |      | 2           |      | μs   |
| Turn-off time   | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$                       | t <sub>off</sub>     |      | 2.3         |      | μs   |
| Cut-off frequency   | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$                       | f <sub>c</sub>       |      | 180         |      | kHz  |

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

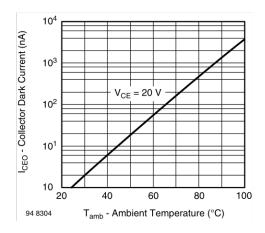


Fig. 2 - Collector Dark Current vs. Ambient Temperature

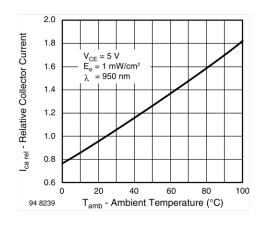


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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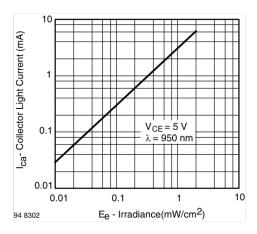


Fig. 4 - Collector Light Current vs. Irradiance

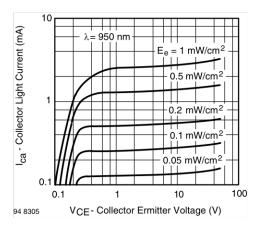


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

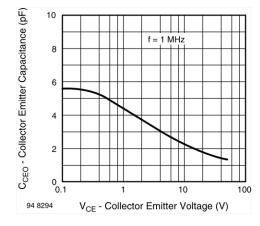


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

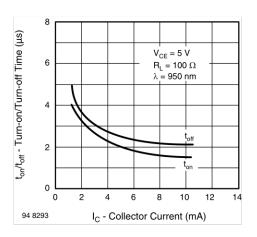


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

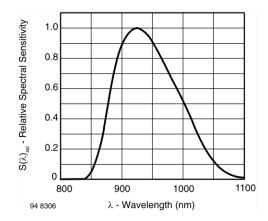


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

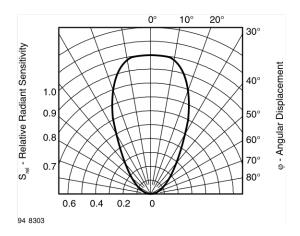
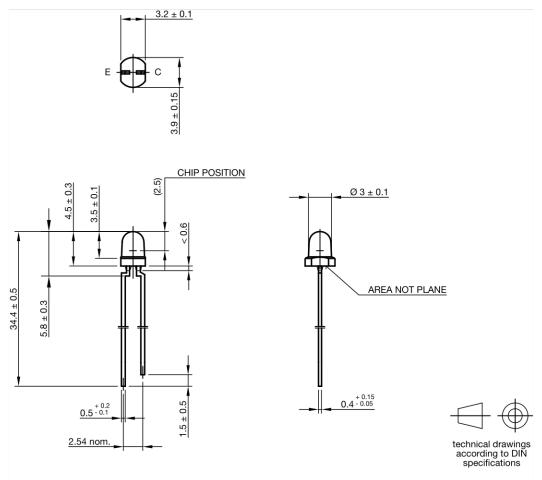


Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement



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#### **PACKAGE DIMENSIONS** in millimeters



Drawing-No.: 6.544-5269.01-4

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